

# HMC273AMS10GE

v05.0416

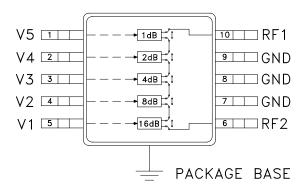
## 1 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

#### Typical Applications

The HMC273AMS10G(E) is ideal for:

- Cellular; UMTS/3G Infrastructure
- ISM, MMDS, WLAN, WiMAX
- Microwave Radio & VSAT
- Test Equipment and Sensors

#### **Functional Diagram**



#### **Features**

RoHs Compliant Product

1 dB LSB Steps to 31 dB

Single Positive Control Per BIT

±0.2 dB Typical Bit Error

Miniature MSOP 10 Package: 14.8mm<sup>2</sup> Included in the HMC-DK004 Designer's Kit

#### **General Description**

The HMC273AMS10G(E) is a general purpose broadband 5-Bit positive control GaAs IC digital attenuator in a 10 lead MSOP plastic package. Covering 0.7 to 3.8 GHz, the insertion loss is typically less than 3 dB. The attenuator bit values are 1 (LSB), 2, 4, 8, and 16 dB for a total attenuation of 31 dB. Accuracy is excellent at ±0.2 dB typical with an IIP3 of up to +46 dBm. Five bit control voltage inputs, toggled between 0 and +3 to +5 volts, are used to select each attenuation state. A single Vdd bias of +3 to +5 volts applied through an external 5K Ohm resistor is required.

## Electrical Specifications,

 $T_A = +25^{\circ}$  C, Vdd = +3V to +5V & VctI = 0/Vdd (Unless Otherwise Stated)

Parameter		Frequency	Min.	Typical	Max.	Units
Insertion Loss		0.7 - 1.4 GHz 1.4 - 2.3 GHz 2.3 - 2.7 GHz 2.7 - 3.8 GHz		1.8 2.3 2.5 2.9	2.4 2.9 3.1 3.5	dB dB dB dB dB
Attenuation Range		0.7 - 3.8 GHz		31		dB
Return Loss (RF1 & RF2, All Atten. States)		0.7 - 1.4 GHz 1.4 - 2.7 GHz 2.7 - 3.8 GHz	10 11 12	14 15 16		dB dB dB
Attenuation Accuracy: (Referenced to Insertion Loss) All Attenuation States All Attenuation States All Attenuation States All Attenuation States		0.7 - 1.4 GHz 1.4 - 2.2 GHz 2.2 - 2.7 GHz 2.7 - 3.8 GHz	± (0.30 + 3% of Atten. Setting) Max ± (0.30 + 4% of Atten. Setting) Max ± (0.40 + 5% of Atten. Setting) Max ± (0.50 + 5% of Atten. Setting) Max		dB dB dB dB	
Input Power for 0.1 dB Compression	Vdd = 5V Vdd = 3V	0.7 - 3.8 GHz		28 26		dBm dBm
Input Third Order Intercept Point (Two-tone Input Power = 0 dBm Each Tone)	Vdd = 5V Vdd = 3V	0.7 - 3.8 GHz		46 45		dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		0.7 - 3.8 GHz		1250 1300		ns ns

# **HMC273A\* PRODUCT PAGE QUICK LINKS**

Last Content Update: 02/23/2017

# COMPARABLE PARTS 🖵

View a parametric search of comparable parts.

## **EVALUATION KITS**

• HMC273A Evaluation Board

## **DOCUMENTATION**

#### **Data Sheet**

 HMC273AMS10GE: 1 dB LSB GaAs MMIC 5-Bit Digital Attenuator, 0.7 to 3.8 GHz Data Sheet

# TOOLS AND SIMULATIONS -

HMC273AMS10GE IBIS Model

## DESIGN RESOURCES 🖵

- HMC273A Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

#### **DISCUSSIONS** •

View all HMC273A EngineerZone Discussions.

## SAMPLE AND BUY 🖵

Visit the product page to see pricing options.

## TECHNICAL SUPPORT 🖳

Submit a technical question or find your regional support number.

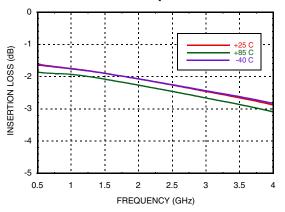
## DOCUMENT FEEDBACK 🖳

Submit feedback for this data sheet.



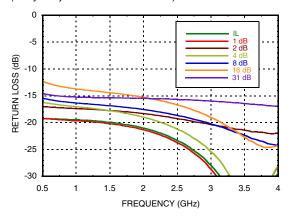
## 1 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

#### Insertion Loss vs. Temperature



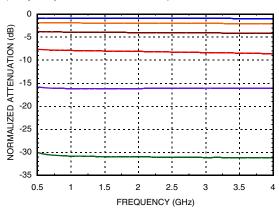
#### Return Loss RF1, RF2

(Only Major States are Shown)

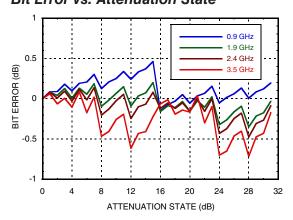


#### **Normalized Attenuation**

(Only Major States are Shown)

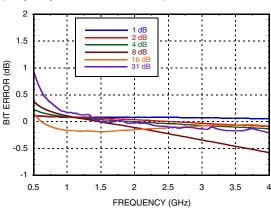


#### Bit Error vs. Attenuation State



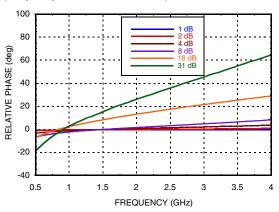
#### Bit Error vs. Frequency

(Only Major States are Shown)



#### Relative Phase vs. Frequency

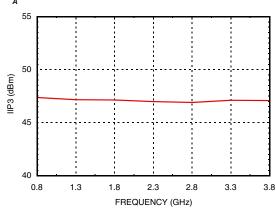
(Only Major States are Shown)



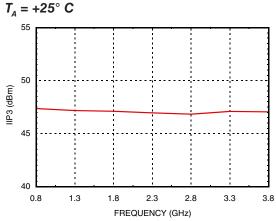
Note: All Data Typical Over Voltage (+3V to +5V)

# 1 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

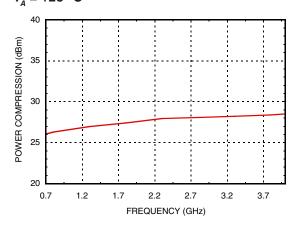
Input IP3 Vs. Frequency @ VDD= 3V,  $T_A = +25^{\circ}$  C



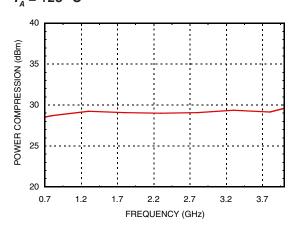
Input IP3 vs. Frequency @ VDD= 5V,



P0.1dB Vs. Frequency @ VDD= 3V,  $T_{A} = +25^{\circ}$  C

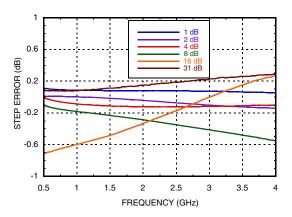


P0.1dB Vs. Frequency @ VDD= 5V  $T_A = +25^{\circ} \text{ C}$ 



Step Error Vs. Frequency

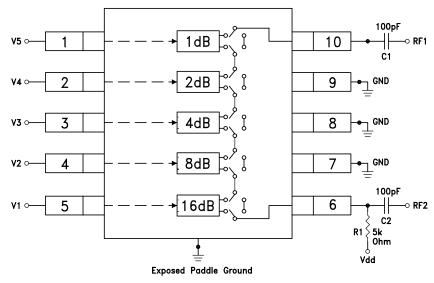
(Only Major States are Shown)





## 1 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

## **Application Circuit**



DC blocking capacitors C1 & C2 are required on RF1 & RF2. Choose C1 =  $C2 = 100 \sim 300$  pF to allow lowest customer specific frequency to pass with minimal loss. R1 = 5K Ohm is required to supply voltage to the circuit through either PIN 6 or PIN 10.

#### **Truth Table**

Control Voltage Input				Attenuation	
V1 16 dB	V2 8 dB	V3 4 dB	V4 2 dB	V5 1 dB	Setting RF1 - RF2
High	High	High	High	High	Reference I.L.
High	High	High	High	Low	1 dB
High	High	High	Low	High	2 dB
High	High	Low	High	High	4 dB
High	Low	High	High	High	8 dB
Low	High	High	High	High	16 dB
Low	Low	Low	Low	Low	31 dB Max. Atten.

Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

## **Absolute Maximum Ratings**

Control Voltage (V1 - V5)	Vdd + 0.5 V
Bias Voltage (Vdd)	+8.0 Vdc
Channel Temperature	150 °C
Continuous Pdiss	0.68 W
Thermal Resistance	95°C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
RF Input Power	+26 dBm
ESD Sensitivity (HBM)	Class 1A

## **Control Voltages**

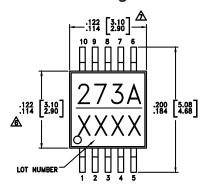
State	Bias Condition	
Low	0 to +0.2 V @ < 1uA Max	
High	Vdd ± 0.2V @ 1uA Max	
Note: $Vdd = +3V$ to $5V \pm 0.2V$		

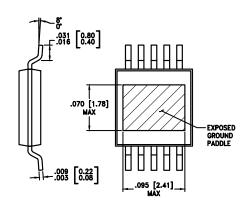


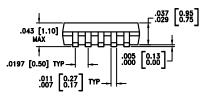


## 1 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

## **Outline Drawing**







#### NOTES:

- 1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY
- 3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 5. CHARACTERS TO BE HELYETICA MEDIUM, .030 HIGH, LASER OR WHITE INK, LOCATED APPROXIMATELY AS SHOWN.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

## Package Information

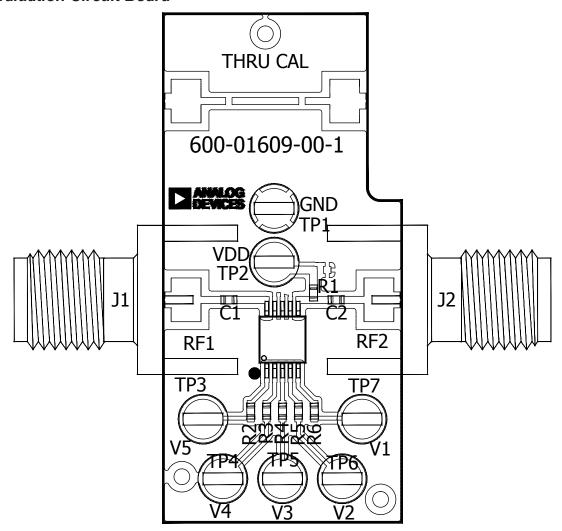
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC273AMS10G	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	<u>273A</u> XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260  $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX



## 1 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

#### **Evaluation Circuit Board**



#### List of Materials for Evaluation PCB EV1HMC273AMS10G[1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J6	DC Pin
R1	5 kOhm Resistor, 0402 Chip
R2, R3, R4	100 Ohm Resistor, 0402 Chip
C1, C2	0402 Chip Capacitor, Select for Lowest Frequency of Operation
U1	HMC273AMS10GE Digital Attenuator
PCB [2]	EV1HMC273AMS10G Evaluation PCB 1.5" x 1.5"

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed ground paddle should be connected directly to the ground plane similar to that shown below. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board as shown is available from Hittite Microwave Corporation upon request.

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Analog Devices Inc.:

HMC273AMS10GETR HMC273AMS10GE EV1HMC273AMS10G